**Resistance to Solvents** 

**Temperature Cycling** 

Solderability

Vibration



Nominal Frequency

23.104MHz

#### ES52C5 F 10 V -23.104M

Series RoHS Compliant (Pb-free) 3.0V 3.2mm x 5mm Ceramic

MIL-STD-202, Method 215

MIL-STD-883, Method 2003

MIL-STD-883, Method 1010, Condition B MIL-STD-883, Method 2007, Condition A

**Control Voltage** 1.5Vdc ±1.0Vdc

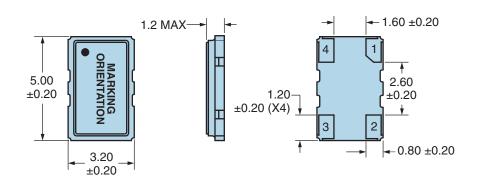
SMD Clipped Sinewave TC(VC)XO

### Operating Temperature Range -30°C to +85°C

riequen	cy otability -
±1.0ppm	Maximum

#### **ELECTRICAL SPECIFICATIONS** Nominal Frequency 23.104MHz Frequency Stability vs. Frequency ±1.0ppm Maximum (at 25°C ±2°C, at Vdd=3.0Vdc, and Vc=1.5Vdc) Tolerance **Frequency Stability** ±1.0ppm Maximum (Inclusive of Operating Temperature Range, at Vdd=3.0Vdc and Vc=1.5Vdc) Frequency Stability vs. Input Voltage ±0.3ppm Maximum (±5%) Frequency Stability vs. Aging ±1ppm/year Maximum (at 25°C) Frequency Stability vs. Load ±0.2ppm Maximum (±1kOhm//±1pF) **Operating Temperature Range** -30°C to +85°C Supply Voltage +3.0Vdc ±5% Input Current 2.0mA Maximum **Output Voltage** 0.7Vp-p Clipped Sinewave Minimum (External DC-Cut capacitor required, 1000pF recommended) Load Drive Capability 10kOhms//10pF **Output Logic Type Clipped Sinewave Control Voltage** 1.5Vdc ±1.0Vdc **Frequency Deviation** ±8ppm Minimum **Transfer Function** Positive Transfer Characteristic Phase Noise -80dBc/Hz at 10Hz Offset, -115dBc/Hz at 100Hz Offset, -135dBc/Hz at 1kHz Offset, and -148dBc/Hz at 10kHz Offset (Typical Values at 12.800MHz) Start Up Time 5mSec Maximum Storage Temperature Range -40°C to +85°C **ENVIRONMENTAL & MECHANICAL SPECIFICATIONS** ESD Susceptibility MIL-STD-883, Method 3015, Class 1, HBM: 1500V **Fine Leak Test** MIL-STD-883, Method 1014, Condition A Flammability UL94-V0 **Gross Leak Test** MIL-STD-883, Method 1014, Condition C Mechanical Shock MIL-STD-883, Method 2002, Condition B **Moisture Resistance** MIL-STD-883, Method 1004 **Moisture Sensitivity** J-STD-020, MSL 1 MIL-STD-202, Method 210, Condition K **Resistance to Soldering Heat**

### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**



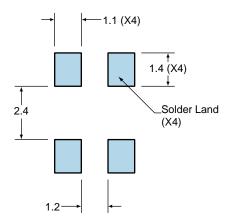
PIN	CONNECTION
1	Voltage Control
2	Ground
3	Output
4	Supply Voltage
LINE	MARKING
LINE 1	MARKING E23.104 E=Ecliptek Designator

CORPORATION

K

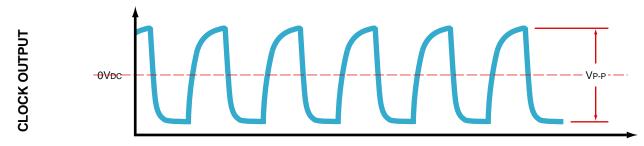
### Suggested Solder Pad Layout

All Dimensions in Millimeters



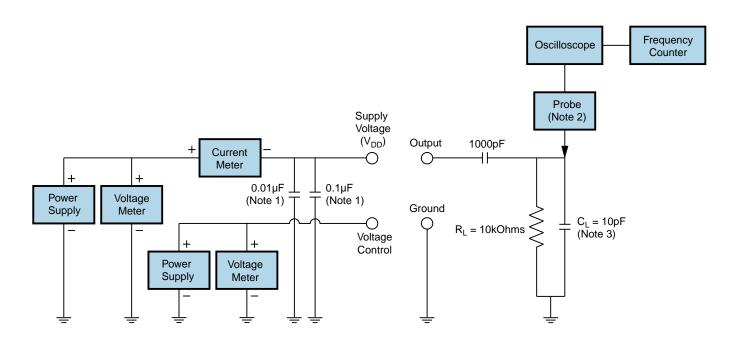
All Tolerances are ±0.1

### **OUTPUT WAVEFORM**





### **Test Circuit for Voltage Control Option**



Note 1: An external 0.1µF low frequency tantalum bypass capacitor in parallel with a 0.01µF high frequency ceramic bypass capacitor close to the package ground and V<sub>DD</sub> pin is required.

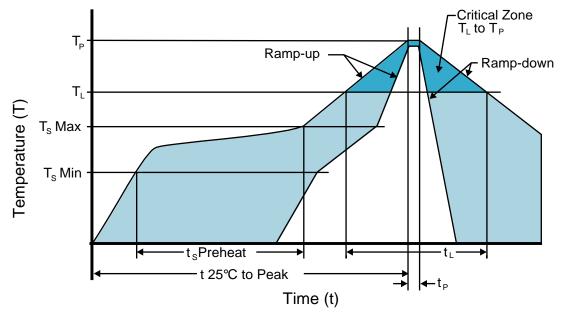
Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value  $\dot{C}_{L}$  includes sum of all probe and fixture capacitance.



### **Recommended Solder Reflow Methods**

ES52C5F10V-23.104M

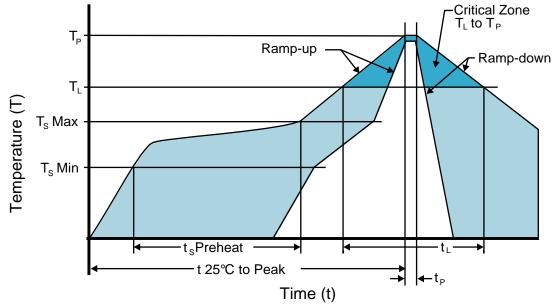


### High Temperature Infrared/Convection

T <sub>s</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	150°C
<ul> <li>Temperature Typical (T<sub>s</sub> TYP)</li> </ul>	175°C
<ul> <li>Temperature Maximum (T<sub>s</sub> MAX)</li> </ul>	200°C
- Time (t <sub>s</sub> MIN)	60 - 180 Seconds
Ramp-up Rate (T⊾ to T <sub>P</sub> )	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T <sub>P</sub> )	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T <sub>P</sub> Target)	250°C +0/-5°C
Time within 5°C of actual peak (t <sub>P</sub> )	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1







### Low Temperature Infrared/Convection 240°C

T <sub>s</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	N/A
- Temperature Typical (T <sub>s</sub> TYP)	150°C
- Temperature Maximum (T <sub>s</sub> MAX)	N/A
- Time (t <sub>s</sub> MIN)	60 - 120 Seconds
Ramp-up Rate (T⊾ to T <sub>P</sub> )	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T <sub>P</sub> )	240°C Maximum
Target Peak Temperature (T <sub>P</sub> Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (t <sub>p</sub> )	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

#### Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.